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10-2004-0100913  
2004 12 02

(21) 10-2004-0033447  
(22) 2004 05 12

(30) JP-P-2003-00146142 2003 05 23 (JP)

(71) 가 가  
2 4-1

(72) 가 3-3-5 가 가  
가 3-3-5 가 가

(74)

:

(54) E L ,

EL

EL , (13) (20) EL , EL , EL , (51) (30) ,  
(13) , (發光光) . (41) EL EL , EL .

1

, , , , ,

1 EL

2 (a) 2 (c) EL  
 3 (a) 3 (c) EL  
 4 (a) 4 (b) EL  
 5 (a) 5 (b) EL  
 6 (a) 6 (f) EL  
 7 EL  
 8 (a) 8 (b) EL

\* \*

11 ...

12 ...

13 ... ( )

20 ... (TFT )

30 ... EL

41 ...

51 ... ( , )

EL , EL ,

, ,

, 2002-217391 , 2 , , 1  
 , 가 , , , , 1  
 2 , , , , , ,  
 , , , , , ,  
 (TFT) , TFT , EL

, 2 EL

가

가

EL

EL

가

2

EL  
(loss)가

EL

EL

EL

EL

EL

(發光光)

EL

EL

1

EL

EL

가 가

400( ) 800( )nm

300nm

(가 )

가

(異方性)

(薄)

EL

EL

( PDA),

2

1

1

1

EL

EL

1

1  
2

2

1

, 가 EL  
 , ,  
 < >  
 ,  
 , EL , TFT , EL  
 , 2 1 ,  
 , EL  
 ,  
 1 , EL  
 (同) 가 (41) , EL (1) (20) (41) (20) EL (30) (51) , (51)  
 51) , (20) (51) (13) (41) , , ,  
 , EL 1 (1) , , EL (20) (18b)  
 , EL (1) , , EL ,  
 , IN/OUT 가 EL (30) EL (1) (20) EL , EL (TFT) (EL) TFT, EL  
 가 (20) (20) (18b) (TFT) (EL) EL (30) , ,  
 IN/OUT , , (20) (20) (18b) (18b) (20) (18b)  
 , EL (71) (1) FPC (72) (61) FPC (18b) (61) (62)  
 ,  
 TFT (20) , , , , (13) (13)  
 (13) 1 , , , , (13) (13) (13) (13) 가 가 (11)  
 400nm 800nm 300nm , , , , 400nm( ) 800n  
 m( )  
 7 1  
 , (51) , (11) (51) (20) (20) EL EL (30) (30) (11) (41)  
 , (11) (11) (11) (11) FPC (61) (61)  
 , EL 1 (11) (11)

(51) 가 (可撓性) EL

8 , EL

(a) . . . , (52) (11) , (20) EL (30) (53) (劣化) . (53) . (53) (CaO) (36) EL (30) (53)

$$(b) \quad (20) \quad \text{EL} \quad (30) \quad 7 \quad , \quad , \quad (41) \quad (11) \quad (51)$$

2 5 , EL

12) , 2 (a)  $(\text{SiH}_4)$  가 , 1 CVD( ) (11) ( -Si)(  
 , ) (光) ( 「 」 「 」 )  
 , , (ablation)  
 , 가 ,  
 가 ,  
 가 ,  
 (a-Si) 가 , 가

(14) . (15) , TEOS  
 VD . CVD , (16)  
 (16) , (16)

(17)

(12)

(18)

SiH<sub>4</sub>)<sup>2</sup> (O<sub>2</sub>)<sup>(c)</sup> 가 CVD (18) (19)  
 ITO (32) CVD (19) (19) (19) (19)  
 (13) (19) (20) (33) (33) (31) (31)  
 (31) (31)

EL, 3 (a) (31)  
 (34), EL (35) (31)  
 (36) (36) (36) (37)  
 H<sub>3</sub>) 가 가 CVD (Si<sub>x</sub>N<sub>y</sub>) (38) (38) (37)  
 (38) EL (30) (3) (b). (SiH<sub>4</sub>) (31) (N) (31)

, 3 (41) TFT EL (41) (41) (11) (51)  
 (3) (c). (51), (耐) 가 (41) (41) (11) (51)

, 4 (12) (11) (11) (11) (11) (11) (11)  
 (4) (a)). (12) (11) (4) (b)). (30) (11) (11)  
 (12) (11) (12) (11) (11) (11) (11)

, (12) (11) (12), (11) (11) (11) (11)  
 (12) (11) (11) (11) (11) (11) (11)

5 (20) (20) (12) (12) (5) (a)). (1) 가 (1) (1) (1)

EL (1) (18b) (71) (72) (1) (71) FPC  
 (61) (62) (71) EL (1) (71) (5)  
 (b)).

, EL (1) (1) (1) (1) (1) (1)

DNA

6 (a) 6 (f) (230) EL (231), (232), (233), (a)  
 EL (100) (b) (240), (230) (241), (234)  
 가 (242),

(57)

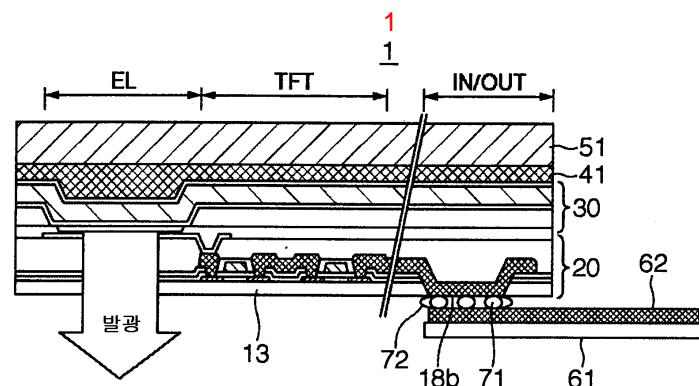
1. ,  
EL (下地層) , EL (發光光)

2. 1 ,  
EL ,

3. 1 2 ,  
400 800nm EL

4. 1 EL

5. 1 ,

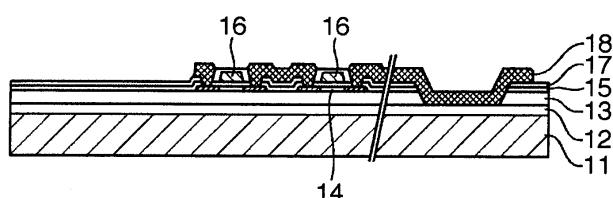


2

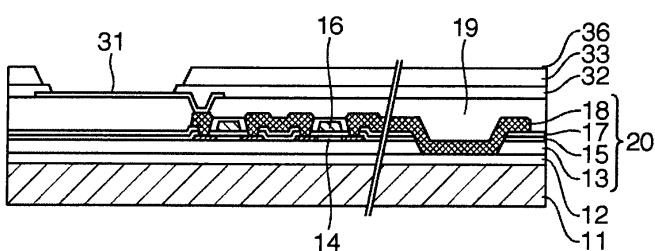
(a)



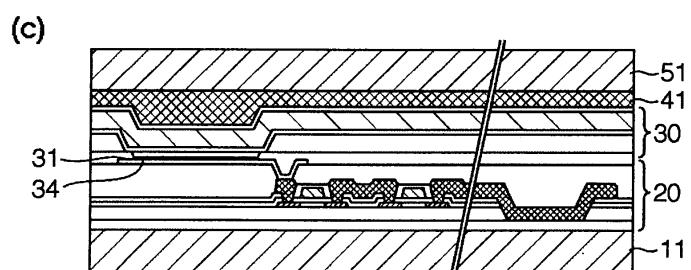
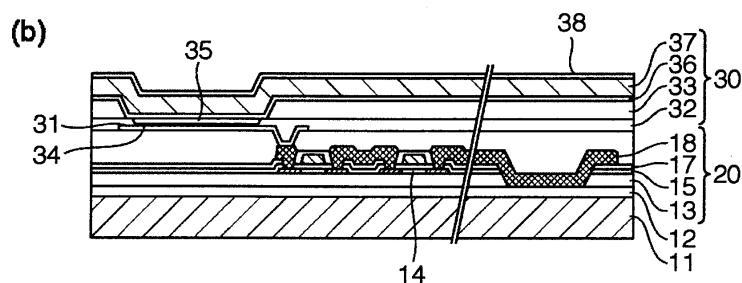
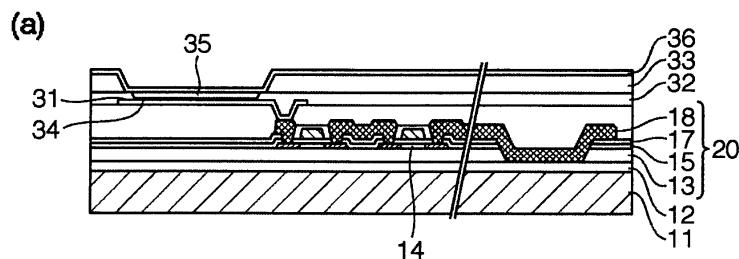
(b)



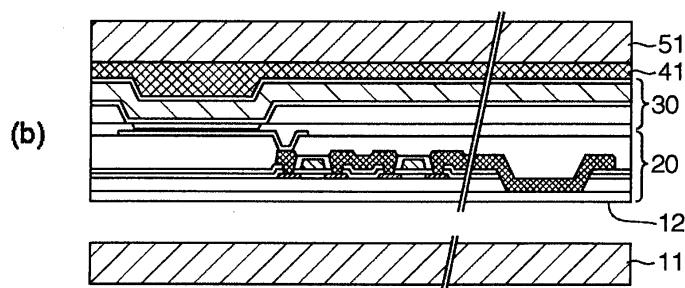
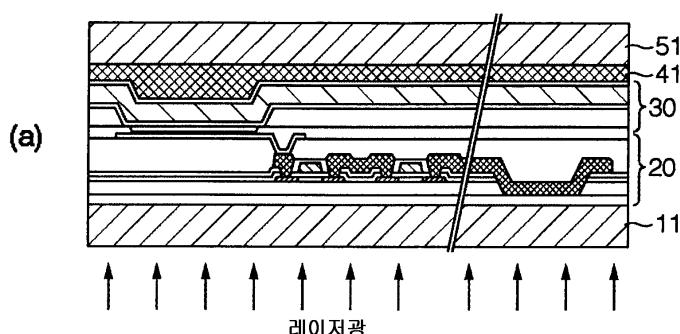
(c)



3

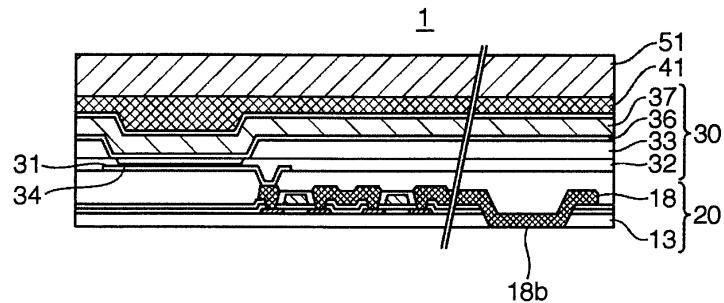


4

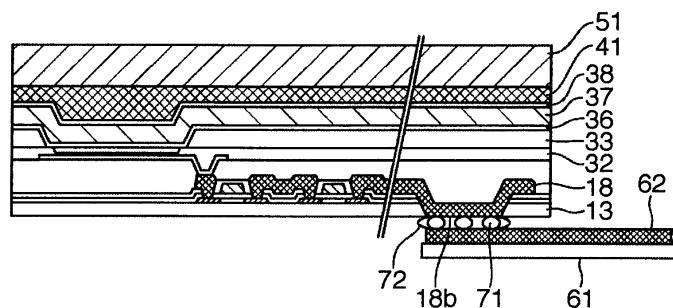


5

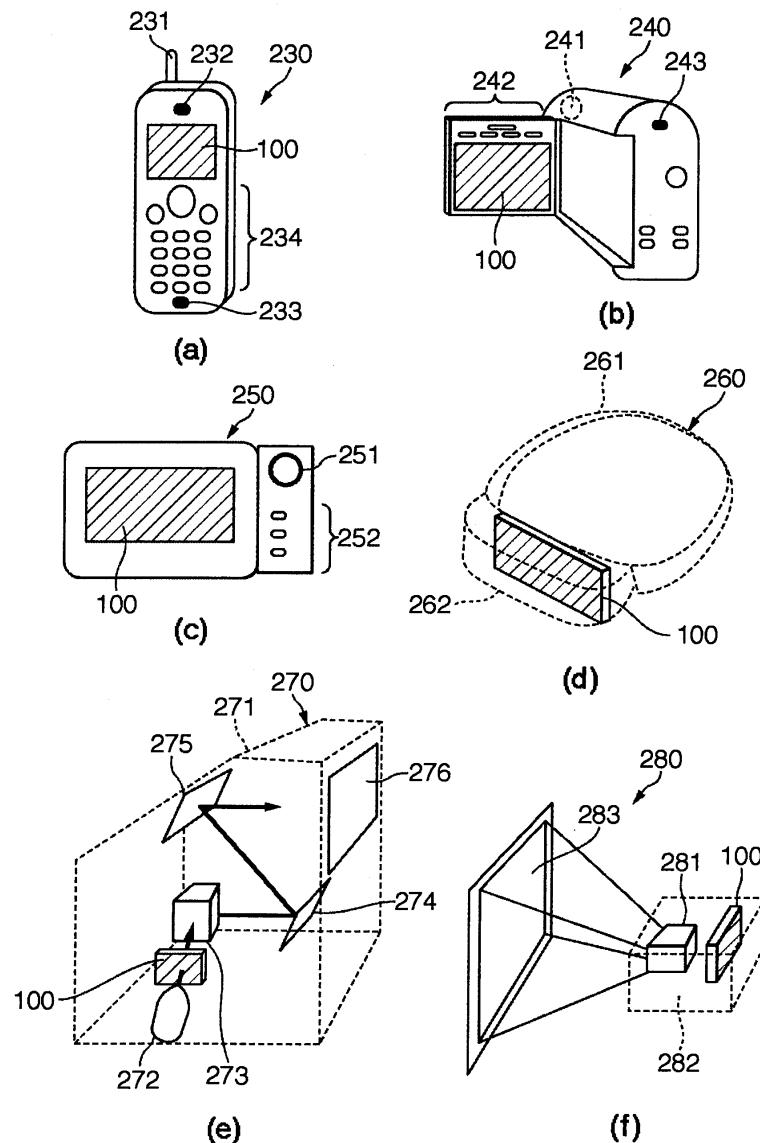
(a)



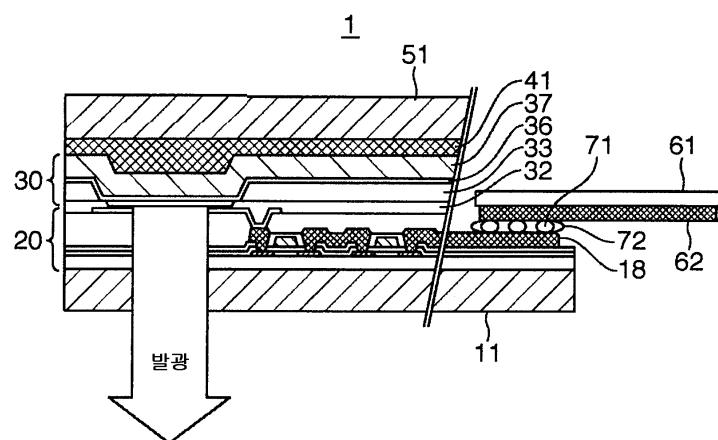
(b)

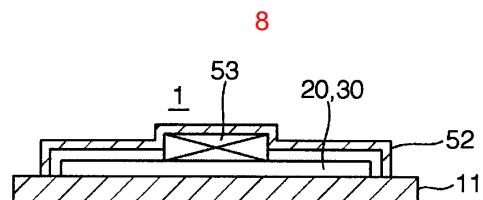


6

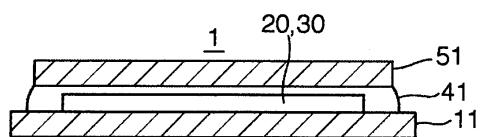


7





(a)



(b)

专利名称(译)	有机EL显示装置，电子装置及其制造方法		
公开(公告)号	<a href="#">KR1020040100913A</a>	公开(公告)日	2004-12-02
申请号	KR1020040033447	申请日	2004-05-12
[标]申请(专利权)人(译)	精工爱普生株式会社		
申请(专利权)人(译)	精工爱普生株式会社		
当前申请(专利权)人(译)	精工爱普生株式会社		
[标]发明人	UTSUNOMIYA SUMIO 우츠노미야스미오 KAMAKURA TOMOYUKI 가마쿠라도모유키		
发明人	우츠노미야스미오 가마쿠라도모유키		
IPC分类号	H05B33/04 H01L51/50 H01L27/32 H01L51/52 H01L21/84 H01L51/56 H01L21/77 H05B33/10 H05B33/06		
CPC分类号	H01L27/3244 H01L51/56 H01L27/1266 H01L27/1214 H01L51/5237 H01L27/3276 H01L51/5253		
代理人(译)	MOON, KI桑		
优先权	2003146142 2003-05-23 JP		
其他公开文献	KR100627097B1		

#### 摘要(译)

提供了一种更薄的片状有机EL显示装置。有机EL显示装置包括：基板51，用作防止水或氧渗透到内部的保护层和膜形成的支撑层；以及薄膜电路层20，用作形成在基层13上的电路。)和有机EL发光元件包括发光层30和用于将层压体粘合到基板的粘合剂层41的层压体，并且有机EL发光构件发射从基层13侧发射的光。结果，可以获得薄的有机EL显示装置。  
1 指数方面 片状，渗透，保护层，支撑层，层压板，粘合层。

